# FEE TRANSMITTAL

### Electronic Version v10

## Stylesheet Version v10

Title of

Method of Improved High K Dielectric-Polysilicon Interface for CMOS Devices Invention

Application Number: 09/941827

Date: 2001-08-29

Ronald A. Weimer First Named Applicant:

Attorney Docket Number: Art Unit: 2813

Examiner: Yennhu B. Huynh

# **TOTAL FEE AUTHORIZED \$ 180**

Patent fees are subject to annual revisions on or about October 1st of each year.

MTI-31532

Fee Description	Fee Code	Amount \$	Fee Paid \$
Submission Of Information Disclosure Stmt Fee	1806	180	180

#### AUTHORIZED BILLING INFORMATION

The commissioner is hereby authorized to charge indicated fees and credit any overpayments to:

Deposit account number: 232053

Access Code

Deposit name: Whyte Hirschboeck Dudek S.C.

Deposit authorized name: Kristine M. Strodthoff

Signature: /kms/

2005-01-18 Date (YYYYMMDD):